

Bipolar Transistor

-160 V, -1.5 A, Low $V_{\text{CE(sat)}}$ PNP Single LFPAK

NST1601CL

This device is bipolar junction transistor featuring high current, low saturation voltage, and high speed switching.

Suitable for automotive applications. AEC-Q101 qualified and PPAP capable. (NSVT1601CLTWG)

Features

- Complement to NST1602CL
- Large Current Capacitance
- Low Collector to Emitter Saturation Voltage
- Thin Profile LFPAK8 3.3 x 3.3 mm Package
- High-Speed Switching
- High Allowable Power Dissipation
- AEC-Q101 Qualified and PPAP Capable (NSVT1601CLTWG)
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Load Switch
- Gate Driver Buffer
- DC-DC Converters

Specifications

ABSOLUTE MAXIMUM RATING at Ta = 25°C

Parameter	Symbol	Value	Unit
Collector to Base Voltage	V_{CBO}	-180	V
Collector to Emitter Voltage	V _{CEO}	-160	V
Emitter to Base Voltage	V _{EBO}	-6	V
Collector Current	I _C	-1.5	Α
Collector Current (Pulse)	I _{CP}	-2.5	Α
Collector Dissipation	P _C (Note 1)	0.8	W
	P _C (Note 2)	2.2	
Junction Temperature	Tj	175	°C
Storage Temperature	Tstg	-55 to +175	°C

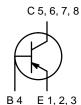
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Mounted on FRB with minimum pad of Copper 2 oz
- 2. Mounted on FRB with 1 in/sq pad of Copper 2 oz



LFPAK8 3.3x3.3, 0.65P CASE 760AD

ELECTRICAL CONNECTION



MARKING DIAGRAM

NST 1601G AWLYW

NST1601 = Specific Device Code A = Assembly Location

WL = Wafer Lot
 Y = Year
 W = Work Week
 G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS at Ta = 25°C

			Value			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
		VCB = -180 V IE = 0 A	-	_	-0.1	μΑ
Emitter Cutoff Current	IEBO	VEB = -6 V IC = 0 A	-	-	-0.1	μΑ
DC Current Gain	hFE1	VCE = -5 V IC = -100 mA	140	-	280	
	hFE2	VCE = -5 V IC = -500 mA	130	_	-	
Gain-Bandwidth Product	fT	VCE = -10 V IC = -100 mA	-	87	-	MHz
Output Capacitance	Cob	VCB = -10 V f = 1 MHz	-	19	-	pF
Collector to Emitter Saturation Voltage	VCE(sat)1	IC = -250 mA IB = -25 mA	-	-0.08	-0.16	V
	VCE(sat)2	IC = -250 mA IB = -50 mA	-	-0.06	-0.12	V
	VCE(sat)3	IC = -500 mA IB = -50 mA	-	-0.1	-0.2	V
Base to Emitter Saturation Voltage	VBE(sat)	IC = -250 mA IB = -25 mA	-	-0.8	-1.2	V
Collector to Base Breakdown Voltage	V(BR)CBO	IC = -10 μA, IE = 0 A	-180	-	_	V
Collector to Emitter Breakdown Voltage	V(BR)CEO	IC = −1 mA, RBE = ∞	-160	-	_	V
Emitter to Base Breakdown Voltage	V(BR)EBO	IE = -10 μA, IC = 0 A	-6	-	-	V
Turn-On Time	t _{on}	See Figure 1	-	50	-	ns
Storage Time	t _{stg}]	-	1150	-	ns
Fall Time	t _f]	_	40	_	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

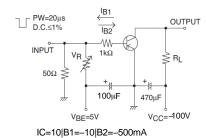


Figure 1. Switching Time Test Circuit

ESD RATING

Parameter	Symbol	Value	Unit	Class
Electrostatic Discharge –Human Body Model	НВМ	>2000, <4000	V	Class 2
Electrostatic Discharge –Machine Model	MM	>400	V	Class M4

TYPICAL CHARACTERISTICS

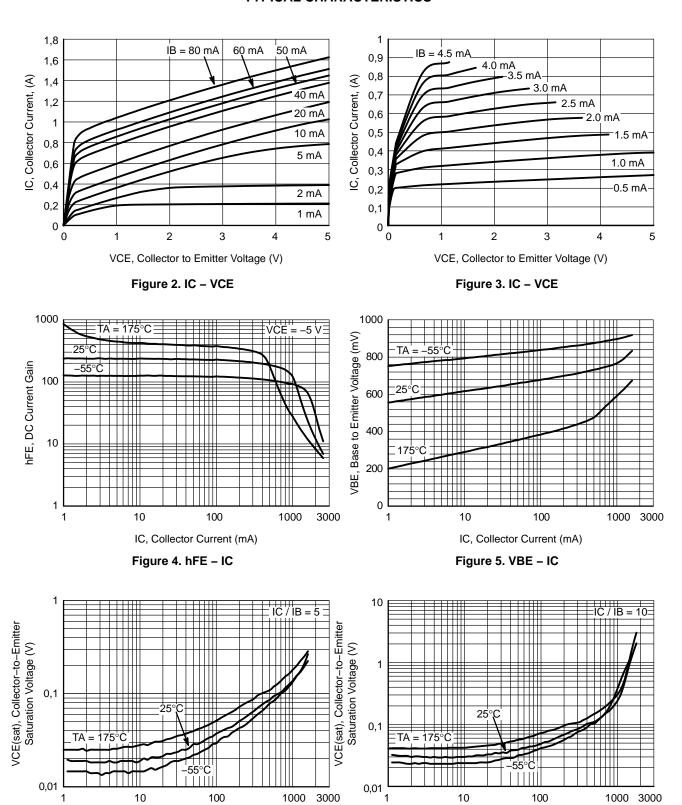


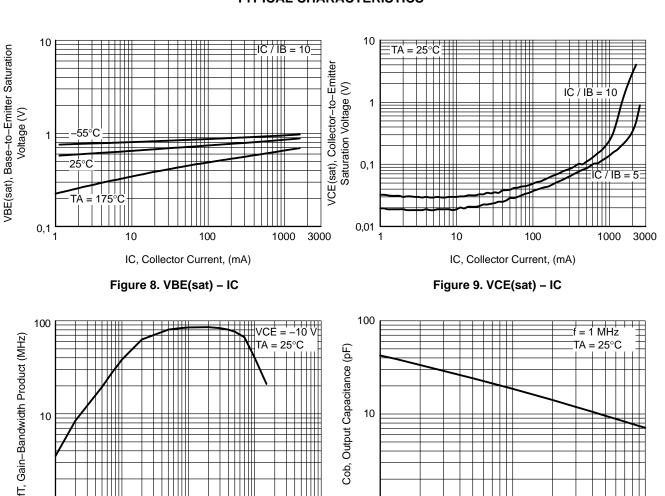
Figure 6. VCE(sat) - IC

IC, Collector Current (mA)

Figure 7. VCE(sat) - IC

IC, Collector Current (mA)

TYPICAL CHARACTERISTICS



IC, Collector Current (mA)

Figure 10. fT - IC

100

10

1

10

0.1

0.0

0.001 0.01

Single Pulse mounted on FRB

0.1

IC, Collector Current (A)

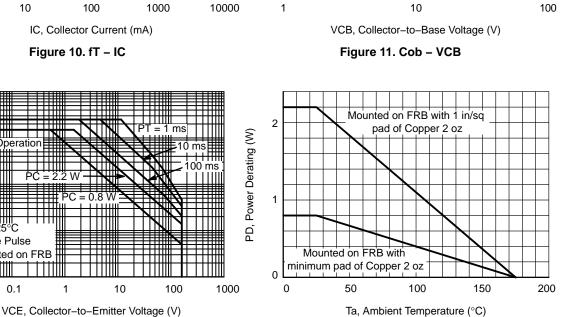


Figure 12. Safe Operating Area

10

1

Figure 13. Power Derating

ORDERING INFORMATION

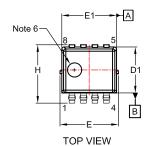
Device	Marking	Package	Shipping (Qty / Packing) [†]
NSVT1601CLTWG	NST1601G	LFPAK8 (Pb–Free / Halogen Free)	3,000 / Tape & Reel
NST1601CLTWG	NST1601G	LFPAK8 (Pb–Free / Halogen Free)	3,000 / Tape & Reel

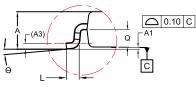
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

onsemi

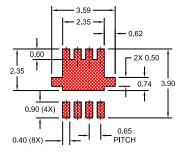
DATE 16 NOV 2020







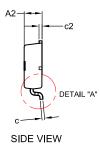
DETAIL 'A'

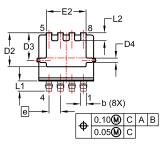


LAND PATTERN RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

LFPAK8 3.3x3.3, 0.65PCASE 760AD ISSUE E





BOTTOM VIEW

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS OR BURRS SHALL NOT EXCEED 0.150mm PER SIDE.
- 4. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 5. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
- 6. OPTIONAL MOLD FEATURE.

DIM	MILLIMETERS			
Diw	MIN.	NOM.	MAX.	
Α	0.95	1.05	1.15	
A1	0.00	0.05	0.10	
A2	0.95	1.00	1.05	
A3		0.15 RE	F	
b	0.27	0.32	0.37	
С	0.12	0.17	0.22	
c2	0.12	0.17	0.22	
D1	2.50	2.60	2.70	
D2	1.82	1.92	2.02	
D3	1.46	1.56	1.66	
D4	0.20	0.25	0.30	
Е	3.20	3.30	3.40	
E1	3.00	3.10	3.20	
E2	2.15	2.25	2.35	
е	0.65 BSC			
Н	3.20	3.30	3.40	
L	0.25	0.37	0.50	
L1	0.48	0.58	0.68	
L2	0.35	0.45	0.55	
Ø	0.45	0.50	0.55	
θ	0°	4°	8°	

GENERIC MARKING DIAGRAM*

XXXXX XXXXX AWLYW

XXXX = Specific Device Code A = Assembly Location

WL = Wafer Lot Y = Year W = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	LFPAK8 3.3x3.3, 0.65P		PAGE 1 OF 1

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For additional information, please contact your local Sales Representative at

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